NTMFS4H01NF

MOSFET – Power, Single, N-Channel, SO-8FL
25 V, 334 A

Features
- Integrated Schottky Diode
- Optimized Design to Minimize Conduction and Switching Losses
- Optimized Package to Minimize Parasitic Inductances
- Optimized material for improved thermal performance
- These Devices are Pb−Free, Halogen Free/BFR Free and are RoHS Compliant

Applications
- High Performance DC-DC Converters
- System Voltage Rails
- Netcom, Telecom
- Servers & Point of Load

MAXIMUM RATINGS (T_J = 25°C unless otherwise stated)

Parameter	Symbol	Value	Units
Drain-to-Source Voltage	V_{DSS}	25	V
Gate-to-Source Voltage	V_{GS}	±20	V
Continuous Drain Current $R_{\theta JA}$ (T_A = 25°C, Note 1)	I_D	54	A
Power Dissipation $R_{\theta JA}$ (T_A = 25°C, Note 1)	P_D	3.2	W
Continuous Drain Current $R_{\theta JC}$ (T_C = 25°C, Note 1)	I_D	334	A
Power Dissipation $R_{\theta JC}$ (T_C = 25°C, Note 1)	P_D	125	W
Pulsed Drain Current (t_p = 10 μs)	I_{DM}	568	A
Single Pulse Drain-to-Source Avalanche Energy (Note 1) (I_L = 57 A_{pk}, L = 0.3 mH)	E_{AS}	487	mJ
Drain to Source dV/dt	dV/dt	7	V/ns
Maximum Junction Temperature	$T_{J(max)}$	150	°C
Storage Temperature Range	T_{STG}	−55 to 150	°C
Lead Temperature Soldering Reflow (SMD Styles Only), Pb-Free Versions (Note 2)	T_{SLD}	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Values based on copper area of 645 mm^2 (or 1 in^2) of 2 oz copper thickness and FR4 PCB substrate.
2. For more information, please refer to our Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.
3. This is the absolute maximum rating. Parts are 100% UIS tested at T_J = 25°C, V_{GS} = 10 V, I_L = 37 A, E_{AS} = 205 mJ.

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V_{GS}	MAX $R_{DS(on)}$	TYP Q_{GTOT}
4.5 V	1.0 mΩ	37.8 nC
10 V	0.7 mΩ	82 nC

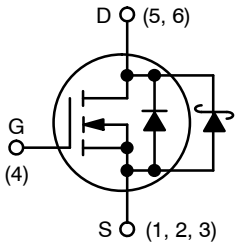
PIN CONNECTIONS

SO8−FL (5 x 6 mm)



(Top View) (Bottom View)

N−CHANNEL MOSFET



ORDERING INFORMATION

See detailed ordering, marking and shipping information on page 7 of this data sheet.

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THERMALCHARACTERISTICS

Parameter	Symbol	Max	Units
Thermal Resistance, Junction-to-Ambient (Note 1 and 4) Junction-to-Case (Note 1 and 4)	 $R_{\theta JA}$ $R_{\theta JC}$	 38.9 1.0	°C/W

4. Thermal Resistance $R_{\theta JA}$ and $R_{\theta JC}$ as defined in JESD51−3.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Parameter	Symbol	Test Condition		Min	Typ	Max	Unit
OFF CHARACTERISTICS							
Drain−to−Source Breakdown Voltage	$V_{(BR)DSS}$	V_{GS} = 0 V, I_D = 250 μA		25			V
Drain−to−Source Breakdown Voltage Temperature Coefficient	$V_{(BR)DSS}/T_J$	I_D = 10 mA reference to 25°C			16		mV/°C
Zero Gate Voltage Drain Current	I_{DSS}	V_{GS} = 0 V, V_{DS} = 20 V	T_J = 25°C			500	μA
Gate−to−Source Leakage Current	I_{GSS}	V_{DS} = 0 V, V_{GS} = +20 V				+100	nA
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	$V_{GS(TH)}$	V_{GS} = V_{DS}, I_D = 250 μA		1.2		2.1	V
Negative Threshold Temperature Coefficient	$V_{GS(TH)}/T_J$	I_D = 10 mA reference to 25°C			3.7		mV/°C
Drain−to−Source On Resistance	$R_{DS(on)}$	V_{GS} = 10 V	I_D = 30 A		0.56	0.7	mΩ
		V_{GS} = 4.5 V	I_D = 30 A		0.79	1	
Forward Transconductance	g_{FS}	V_{DS} = 12 V, I_D = 20 A			101		S
CHARGES, CAPACITANCES & GATE RESISTANCE							
Input Capacitance	C_{ISS}	V_{GS} = 0 V, f = 1 MHz, V_{DS} = 12 V			5538		pF
Output Capacitance	C_{OSS}				3416		
Reverse Transfer Capacitance	C_{RSS}				175.3		
Total Gate Charge	$Q_{G(TOT)}$	V_{GS} = 4.5 V, V_{DS} = 12 V; I_D = 30 A			37.8		nC
Threshold Gate Charge	$Q_{G(TH)}$				2.3		
Gate−to−Source Charge	Q_{GS}				11.8		
Gate−to−Drain Charge	Q_{GD}				8		
Total Gate Charge	$Q_{G(TOT)}$	V_{GS} = 10 V, V_{DS} = 12 V; I_D = 30 A			82		nC
Gate Resistance	R_G	T_A = 25°C			1.3	2	Ω
SWITCHING CHARACTERISTICS, V_{GS} = 4.5 V (Note 5)							
Turn−On Delay Time	$t_{d(ON)}$	V_{GS} = 4.5 V, V_{DD} = 12 V, I_D = 15 A, R_G = 3.0 Ω			16.9		ns
Rise Time	t_r				42.3		
Turn−Off Delay Time	$t_{d(OFF)}$				46.3		
Fall Time	t_f				30.9		
SWITCHING CHARACTERISTICS, V_{GS} = 10 V (Note 5)							
Turn−On Delay Time	$t_{d(ON)}$	V_{GS} = 11.5 V, V_{DD} = 12 V, I_D = 15 A, R_G = 3.0 Ω			10.9		ns
Rise Time	t_r				33.2		
Turn−Off Delay Time	$t_{d(OFF)}$				58.3		
Fall Time	t_f				23.3		
DRAIN−SOURCE DIODE CHARACTERISTICS							
Forward Diode Voltage	V_{SD}	V_{GS} = 0 V, I_S = 2.0 A	T_J = 25°C		0.35	0.6	V
			T_J = 125°C		0.27		
Reverse Recovery Time	t_{RR}	V_{GS} = 0 V, dIS/dt = 100 A/μs, I_S = 30 A			66.7		ns
Charge Time	t_a				33.1		
Discharge Time	t_b				33.6		
Reverse Recovery Charge	Q_{RR}				90		nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. Pulse Test: pulse width ≤ 300 μs, duty cycle ≤ 2%.
6. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS

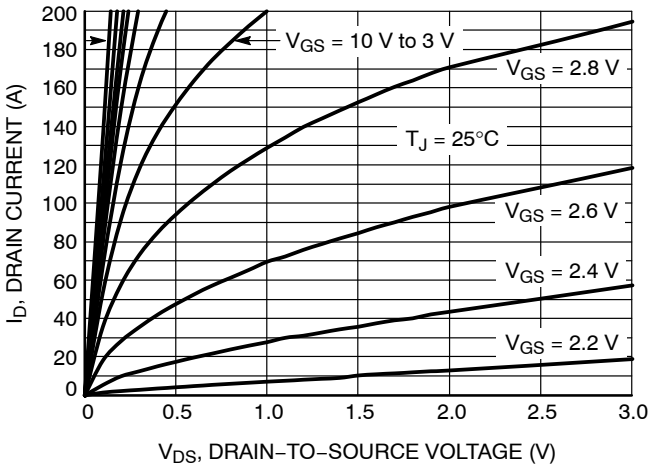


Figure 1. On−Region Characteristics

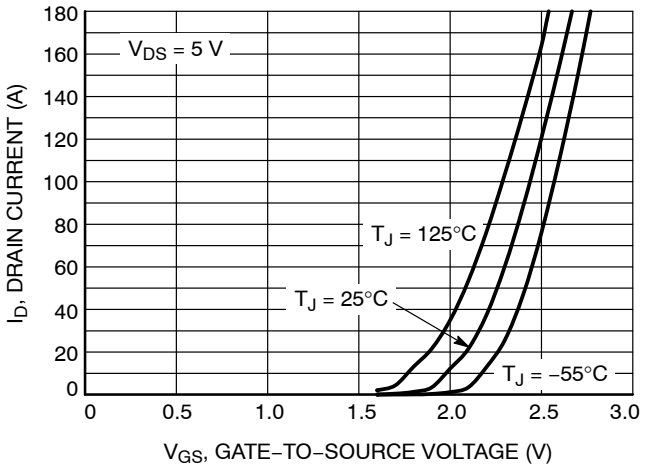


Figure 2. Transfer Characteristics

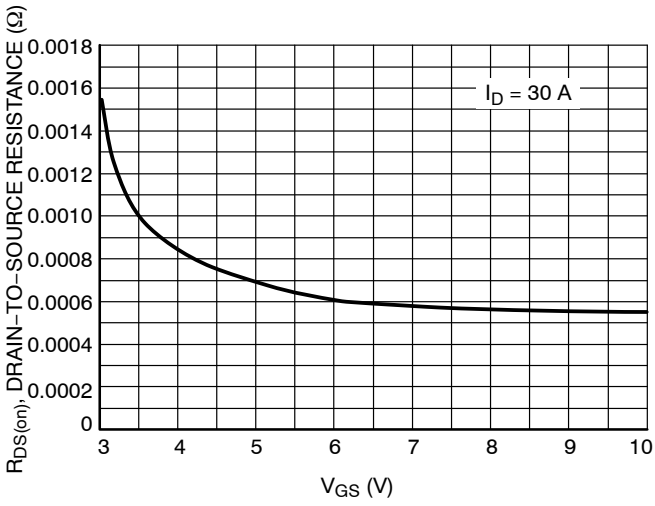


Figure 3. On−Resistance vs. V_{GS}

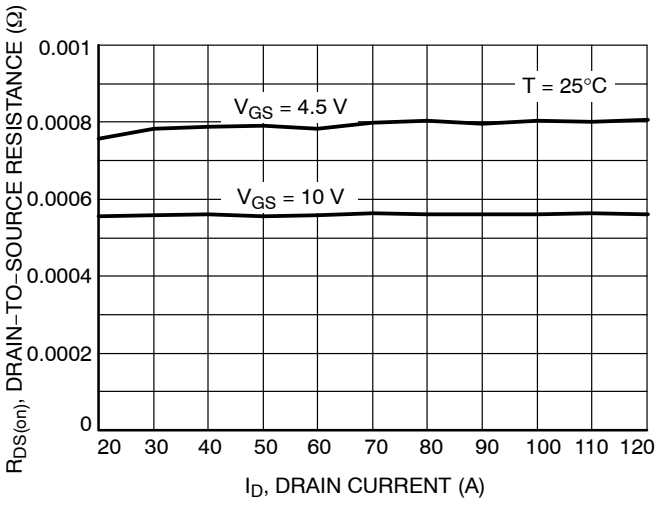


Figure 4. On−Resistance vs. Drain Current and Gate Voltage

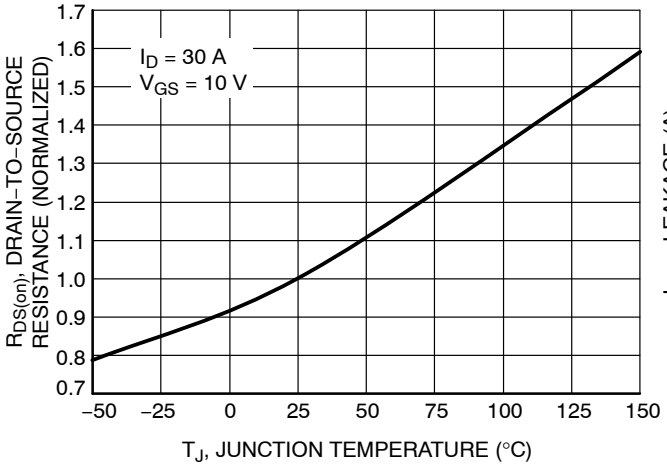


Figure 5. On−Resistance Variation with Temperature

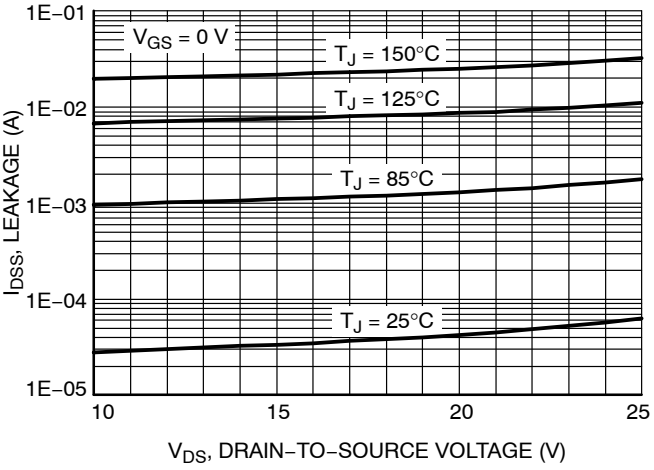


Figure 6. Drain−to−Source Leakage Current vs. Voltage

TYPICAL CHARACTERISTICS

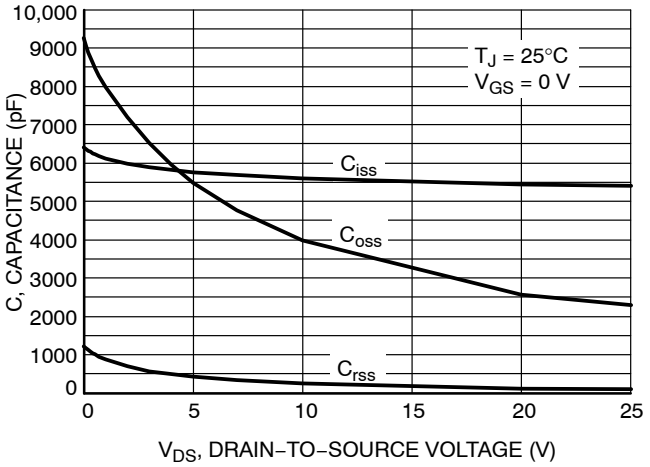


Figure 7. Capacitance Variation

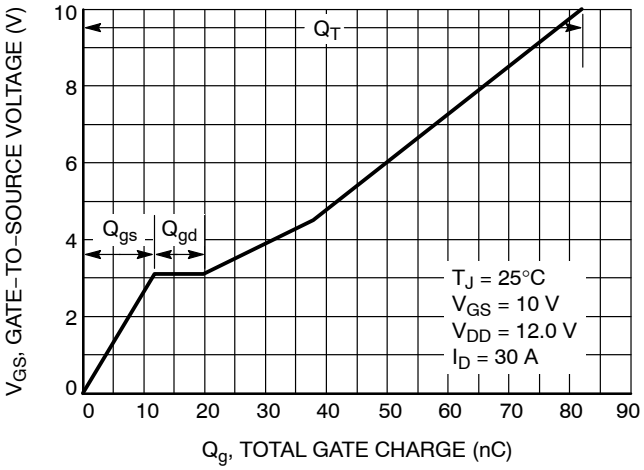


Figure 8. Gate−to−Source and Drain−to−Source Voltage vs. Total Charge

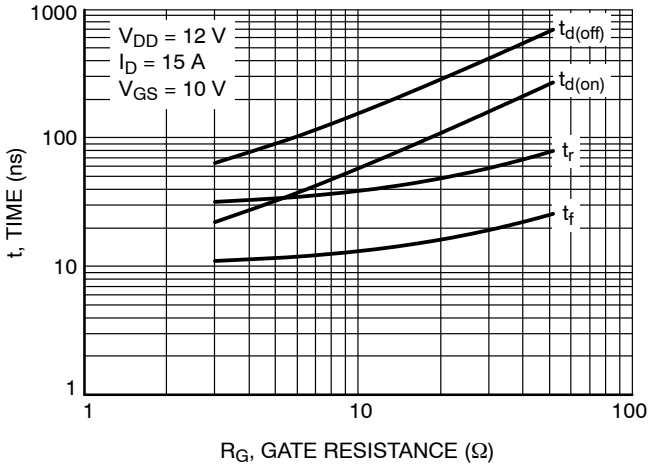


Figure 9. Resistive Switching Time Variation vs. Gate Resistance

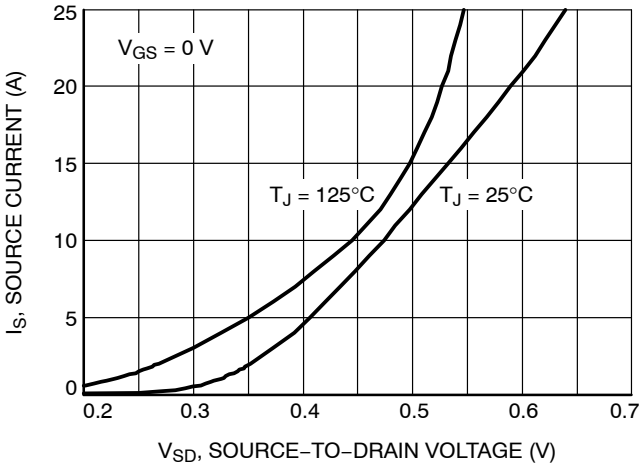


Figure 10. Diode Forward Voltage vs. Current

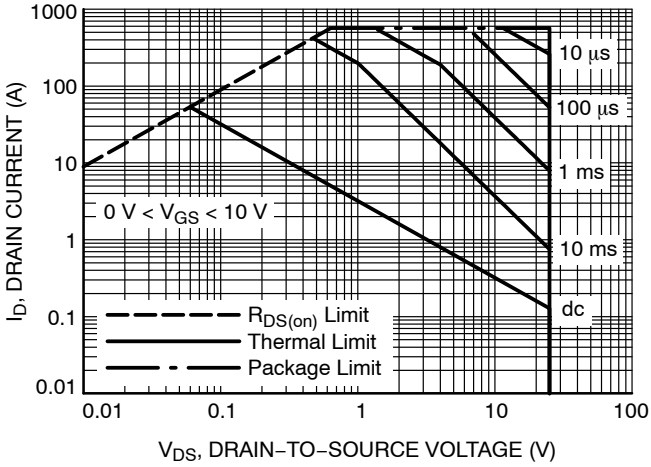


Figure 11. Maximum Rated Forward Biased Safe Operating Area

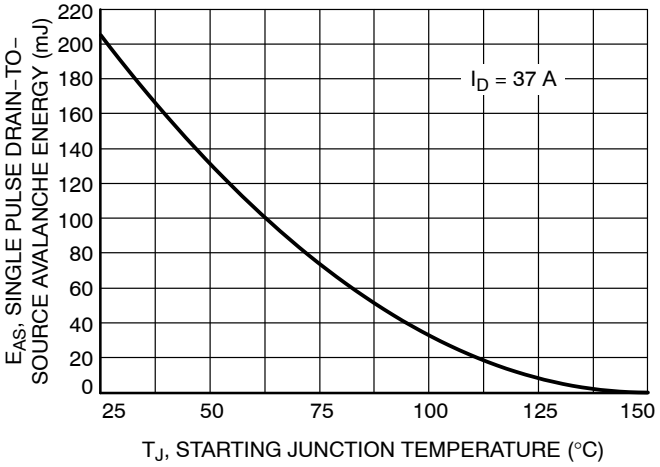


Figure 12. Maximum Avalanche Energy vs. Starting Junction Temperature

TYPICAL CHARACTERISTICS

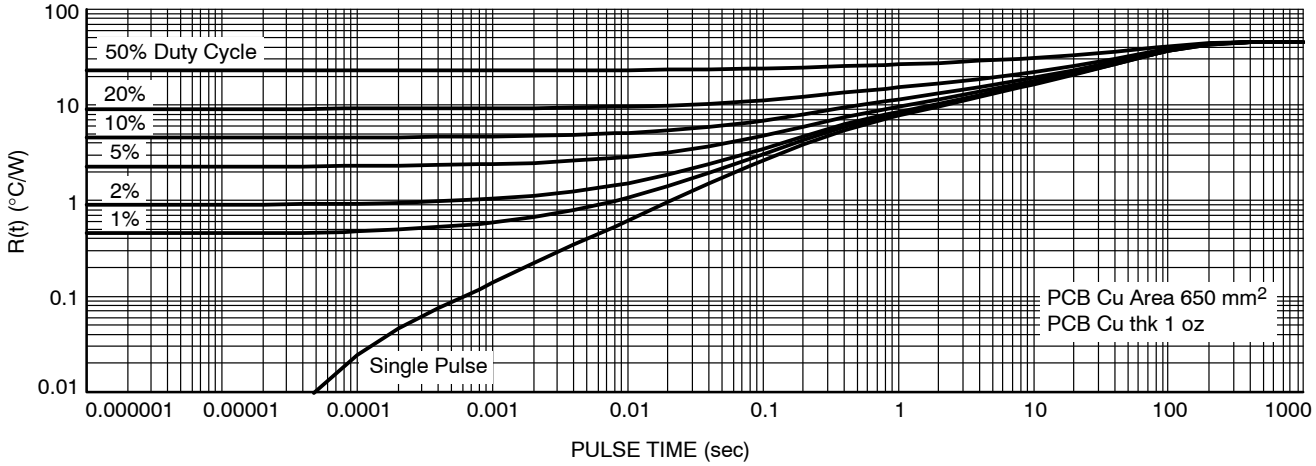


Figure 13. Thermal Characteristics

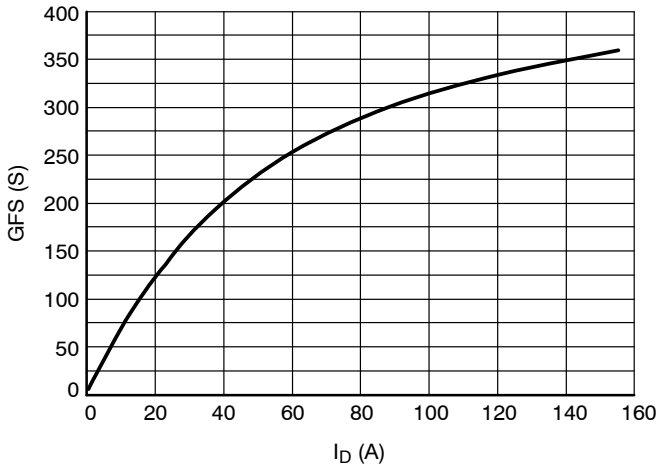


Figure 14. GFS vs. I_D

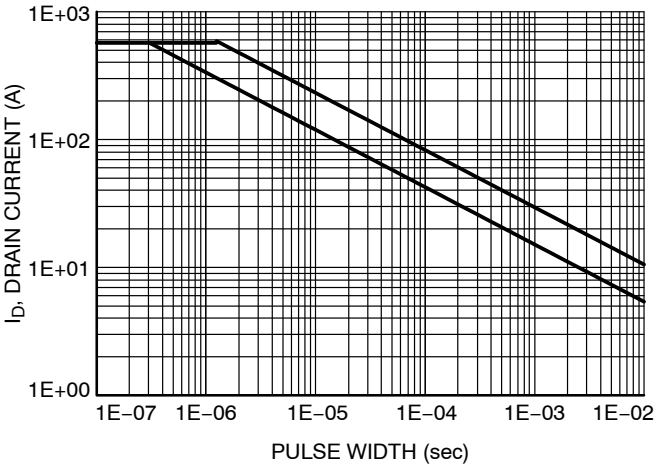
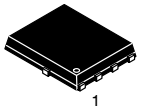


Figure 15. Avalanche Characteristics

ORDERING INFORMATION

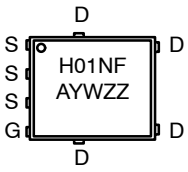
Device	Package	Shipping†
NTMFS4H01NFT1G	SO8−FL (Pb-Free)	1500 / Tape & Reel
NTMFS4H01NFT3G	SO8−FL (Pb-Free)	5000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

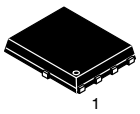


SO−8 FLAT LEAD
CASE 488AA
STYLE 1

MARKING DIAGRAM



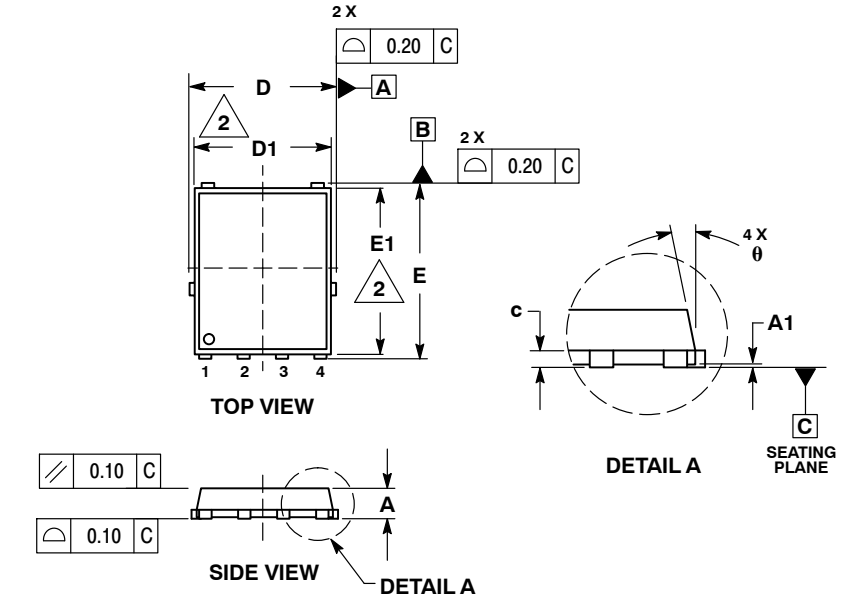
A = Assembly Location
Y = Year
W = Work Week
ZZ = Lot Traceability



SCALE 2:1

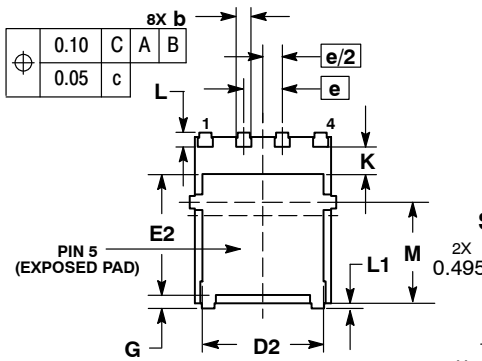
DFN5 5x6, 1.27P
(SO−8FL)
CASE 488AA
ISSUE N

DATE 25 JUN 2018

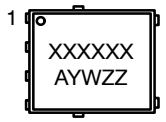


NOTES:
1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION D1 AND E1 DO NOT INCLUDE MOLD FLASH PROTRUSIONS OR GATE BURRS.

	MILLIMETERS		
DIM	MIN	NOM	MAX
A	0.90	1.00	1.10
A1	0.00	–––	0.05
b	0.33	0.41	0.51
c	0.23	0.28	0.33
D	5.00	5.15	5.30
D1	4.70	4.90	5.10
D2	3.80	4.00	4.20
E	6.00	6.15	6.30
E1	5.70	5.90	6.10
E2	3.45	3.65	3.85
e	1.27 BSC		
G	0.51	0.575	0.71
K	1.20	1.35	1.50
L	0.51	0.575	0.71
L1	0.125 REF		
M	3.00	3.40	3.80
θ	0 °	–––	12 °



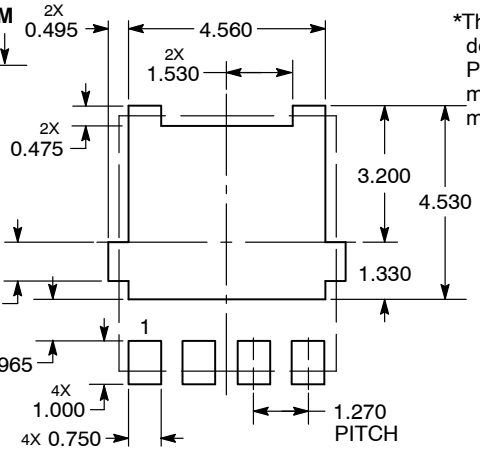
GENERIC MARKING DIAGRAM*



XXXXXX = Specific Device Code
A = Assembly Location
Y = Year
W = Work Week
ZZ = Lot Traceability

*This information is generic. Please refer to device data sheet for actual part marking. Pb−Free indicator, “G” or microdot “ ▪”, may or may not be present. Some products may not follow the Generic Marking.

RECOMMENDED SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

STYLE 1:
PIN 1. SOURCE
2. SOURCE
3. SOURCE
4. GATE
5. DRAIN

STYLE 2:
PIN 1. ANODE
2. ANODE
3. ANODE
4. NO CONNECT
5. CATHODE

*For additional information on our Pb−Free strategy and soldering details, please download the **onsemi** Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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DESCRIPTION:	**DFN5 5x6, 1.27P (SO−8FL)**		**PAGE 1 OF 1**

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Parça koduyla arama

Üretici parça numarasını yazın; stok ve fiyatı hemen görün.

www.entegreci.com

Ürün kategorileri

Entegreden kapasitöre tüm elektronik komponent kategorileri.

Kategorilere göz atın

Üreticiler

Aradığınız üreticinin ürünlerini tek sayfada inceleyin.

Üreticileri görün

Toplu alım ve teklif

Listede olmayan ya da yüksek adetli parçalar için teklif isteyin.

Teklif isteyin

www.entegreci.com | **destek@entegreci.com** | **0850 305 90 34**

Entegreci is an online electronic components store based in Türkiye. Search by manufacturer part number to see stock, prices and datasheets for integrated circuits, microcontrollers, transistors, passive components and connectors, or request a quote for parts that are not listed.

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